SMS05C, SMS12C, SMS15C, SMS24C

5-Line Transient Voltage Suppressor Array

This 5-line voltage transient suppressor array is designed for application requiring transient voltage protection capability. It is intended for use in over-transient voltage and ESD sensitive equipment such as computers, printers, automotive electronics, networking communication and other applications. This device features a monolithic common anode design which protects five independent lines in a single SC-74 package.

Features

- Protects up to 5 Lines in a Single SC-74 Package
- Peak Power Dissipation 350 W (8 \times 20 µs Waveform)
- ESD Rating of Class 3B (Exceeding 8.0 kV) per Human Body Model and Class C (Exceeding 400 V) per Machine Model
- Compliance with IEC 61000-4-2 (ESD) 15 kV (Air), 8.0 kV (Contact)
- Flammability Rating of UL 94 V-0
- These are Pb-Free Devices

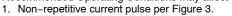
Applications

- Hand–Held Portable Applications
- Networking and Telecom
- Automotive Electronics
- Serial and Parallel Ports
- Notebooks, Desktops, Servers

MAXIMUM RATINGS (T_J = 25°C unless otherwise specified)

Symbol	Rating	Value	Unit
P _{PK} 1	Peak Power Dissipation 8 \times 20 μs Double Exponential Waveform (Note 1)	350	W
TJ	Operating Junction Temperature Range	-40 to 150	°C
T _{STG}	Storage Temperature Range	-55 to 150	°C
TL	Lead Solder Temperature (10 s)	260	°C
ESD	Human Body Model (HBM) Machine Model (MM) IEC 61000-4-2 Air (ESD) IEC 61000-4-2 Contact (ESD)	>8000 >400 >15000 >8000	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

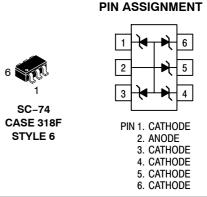




ON Semiconductor®

http://onsemi.com

SC-74 FIVE TRANSIENT **VOLTAGE SUPPRESSOR 350 W PEAK POWER**



MARKING DIAGRAM



x = SMS05C:J

- = SMS12C:K
- = SMS15C:L = SMS24C:M
- = Date Code
- . = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
SMS05CT1G		
SMS12CT1G	SC-74	3000/Tape & Reel
SMS15CT1G	(Pb-Free)	
SMS24CT1G		

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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SMS05C, SMS12C, SMS15C, SMS24C

SMS05C ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise specified)

Parameter	Symbol	Symbol Conditions		Тур	Max	Unit
Reverse Working Voltage	V _{RWM}	(Note 2)			5.0	V
Breakdown Voltage	V _{BR}	I _T = 1.0 mA (Note 3) 6.2			7.2	V
Reverse Leakage Current	I _R	V _{RWM} = 5.0 V			5.0	μA
Clamping Voltage	V _C	I_{PP} = 5.0 A (8 \times 20 μs Waveform)			9.8	V
Clamping Voltage	V _C	I_{PP} = 24 A (8 \times 20 μ s Waveform)			14.5	V
Maximum Peak Pulse Current	I _{PP}	8 \times 20 μ s Waveform			24	А
Capacitance	CJ	$V_R = 0 V$, f = 1.0 MHz (Line to GND)		260	400	pF

SMS12C ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V _{RWM}	(Note 2)			12	V
Breakdown Voltage	V _{BR}	I _T = 1.0 mA (Note 3)	13.3		15	V
Reverse Leakage Current	I _R	V _{RWM} = 12 V		0.001	1.0	μA
Clamping Voltage	V _C	I_{PP} = 5.0 A (8 \times 20 μs Waveform)			19	V
Clamping Voltage	V _C	I_{PP} = 15 A (8 \times 20 μs Waveform)			23	V
Maximum Peak Pulse Current	I _{PP}	8 \times 20 μs Waveform			15	А
Capacitance	CJ	$V_R = 0 V$, f = 1.0 MHz (Line to GND)		120	150	pF

SMS15C ELECTRICAL CHARACTERISTICS (T_J = 25°C, unless otherwise specified) (See Note 4)

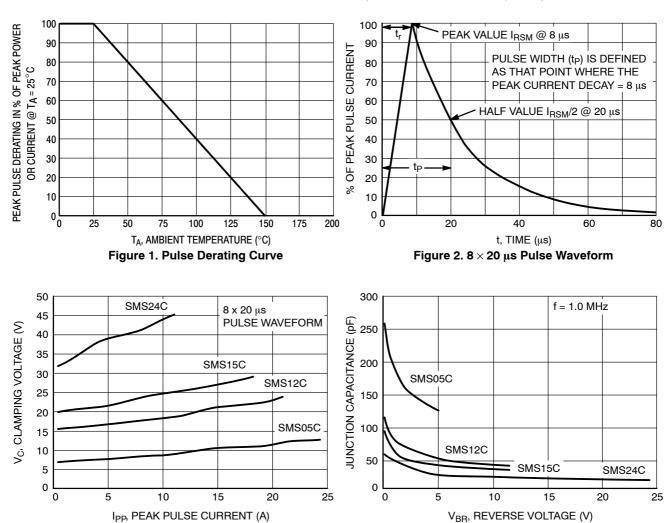
Parameter	Symbol	mbol Conditions		Тур	Max	Unit
Reverse Working Voltage	V _{RWM}	(Note 2)			15	V
Breakdown Voltage	V _{BR}	I _T = 1.0 mA (Note 3)	17		19	V
Reverse Leakage Current	I _R	V _{RWM} = 15 V		0.05	1.0	μΑ
Clamping Voltage	V _C	I_{PP} = 5.0 A (8 \times 20 μs Waveform)			24	V
Clamping Voltage	V _C	I_{PP} = 12 A (8 \times 20 μ s Waveform)			29	V
Maximum Peak Pulse Current	I _{PP}	8 \times 20 μ s Waveform			12	А
Capacitance	CJ	$V_R = 0 V$, f = 1.0 MHz (Line to GND)		95	125	pF

SMS24C ELECTRICAL CHARACTERISTICS (T_J = 25° C, unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V _{RWM}	(Note 2)			24	V
Breakdown Voltage	V _{BR}	I _T = 1.0 mA (Note 3)	26.7		32	V
Reverse Leakage Current	I _R	V _{RWM} = 24 V		0.001	1.0	μA
Clamping Voltage	V _C	I_{PP} = 5.0 A (8 \times 20 μs Waveform)			40	V
Clamping Voltage	V _C	I_{PP} = 8 A (8 \times 20 μ s Waveform)			44	V
Maximum Peak Pulse Current	I _{PP}	$8 \times 20 \mu s$ Waveform			8.0	А
Capacitance	CJ	$V_R = 0 V$, f = 1.0 MHz (Line to GND)		60	75	pF

2. TVS devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.
3. V_{BR} is measured at pulse test current I_T.
4. Parametrics are the same for the Pb–Free packages, which are suffixed with a "G".

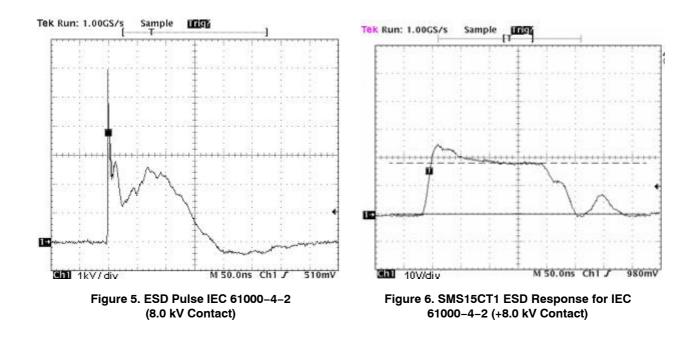
SMS05C, SMS12C, SMS15C, SMS24C



TYPICAL PERFORMANCE CURVES (T_J = 25° C unless otherwise specified)

Figure 3. Clamping Voltage vs. Peak Pulse Current





SMS05C, SMS12C, SMS15C, SMS24C

TYPICAL COMMON ANODE APPLICATIONS

A 5 TVS junction common anode design in a SC-74 package protects four separate lines using only one package. This adds flexibility and creativity to PCB design especially

when board space is at a premium. A simplified example of SMS05C Series Device applications is illustrated below.

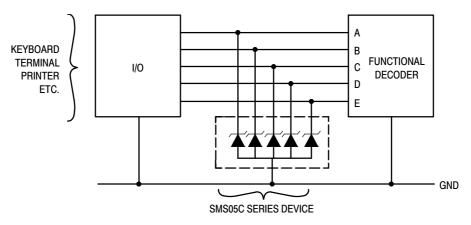
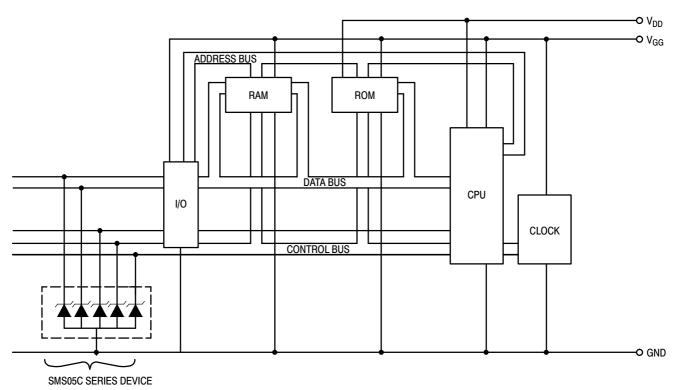


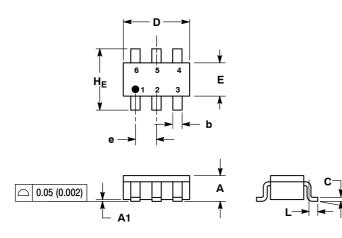
Figure 7. Computer Interface Protection





PACKAGE DIMENSIONS

SC-74 CASE 318F-05 **ISSUE M**



- NOTES DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS 3.
- OF BASE MATERIAL. 318F-01. -02. -03. -04 OBSOLETE. NEW 4. STANDARD 318F-05.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.90	1.00	1.10	0.035	0.039	0.043	
A1	0.01	0.06	0.10	0.001	0.002	0.004	
b	0.25	0.37	0.50	0.010	0.015	0.020	
с	0.10	0.18	0.26	0.004	0.007	0.010	
D	2.90	3.00	3.10	0.114	0.118	0.122	
E	1.30	1.50	1.70	0.051	0.059	0.067	
е	0.85	0.95	1.05	0.034	0.037	0.041	
L	0.20	0.40	0.60	0.008	0.016	0.024	
HE	2.50	2.75	3.00	0.099	0.108	0.118	
θ	0°	-	10°	0°	-	10°	

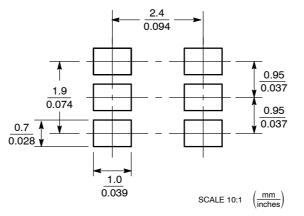
STYLE 6: PIN 1. CATHODE 2. ANODE

3. CATHODE

4 CATHODE 5. CATHODE

6. CATHODE





*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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